Strictly Confidential (For Internal and Restricted Use only) Seni or School Certificate Examination Marking Scheme - Physics (Code 55/1/2)

- 1. The marking scheme provides general guidelines to reduce subjectivity in the marking. The answers given in the marking scheme are suggested answers. The content is thus indicated. If a student has given any other answer, which is different from the one given in the marking scheme, but conveys the meaning correctly, such answers should be given full weight age.
- 2. In value based questions, any other individual response with suitable justification should also be accepted even if there is no reference to the text.
- 3. Evaluation is to be done as per instructions provided in the marking scheme. It should not be done according to one's own interpretation or any other consideration. Marking scheme should be adhered to and religiously followed.
- 4. If a question has parts, please a wardinthe right hand side for each part. Marks a warded for different part of the question should then be totaled up and written in the left hand margin and circled.
- 5. If a question does not have any parts, narks are to be awarded in the left hand margin only.
- 6. If a candidate has attempted an extra question, marks obtained in the question attempted first should be retained and the other answer should be scored out.
- 7. No marks are to be deducted for the cumulative effect of an error. The student should be penalized only once
- 8. Deduct ½ mark for writing wrong units, missing units, in the final answer to numerical problems.
- 9. For mul a can be taken as implied from the calculations even if not explicitly written.
- 10. In short answer type question, asking for two features / characteristics / properties if a candidate writes three features, characteristics / properties or more, only the correct two should be evaluated
- 11. Full marks should be a warded to a candidate if his / her answer in a numerical problem is close to the value given in the scheme.
- 12 In compliance to the judgement of the Hon'ble Supreme Court of India, Board has decided to provide photocopy of the answer book(s) to the candidates who will apply for it along with the requisite fee from 2012 examination. Therefore, it is all the more important that the evaluation is done strictly as per the value points given in the marking scheme so that the Board could be in a position to defend the evaluation at any forum.
- 13. The Examiner shall also have to certify in the answer book that they have evaluated the answer book strictly in accordance with the value points given in the marking scheme and correct set of question paper.
- 14. Every Examiner shall also ensure that all the answers are evaluated, marks carried over to the title paper, correctly totaled and written in figures and words.
- 15. In the past it has been observed that the following are the common types of errors committed by the Exa miners
 - Leaving ans wer or part thereof unassessed in an ans wer script.
 - Giving more marks for an answer than assigned to it or deviation from the marking scheme.
 - Wrong transference of marks from the inside pages of the answer book to the title page.
 - Wr ong question wise totaling on the title page.
 - Wrong totaling of marks of the two columns on the title page.
 - Wrong grand total.
 - Marks in words and figures not tall ying.
 - Wrong transference to marks from the answer book to a ward list.
 - Ans wer marked as correct () but marks not a warded.
 - Half or part of ans wer marked correct () and the rest as wrong () but no marks a warded
- 16. Any unassessed portion, non carrying over of marks to the title page or totaling error detected by the candidate shall damage the prestige of all the personnel engaged in the evaluation work as also of the Board. Hence in order to uphold the prestige of all concerned, it is again reiterated that the instructions be followed meticulously and judiciously.

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MARKI NG SCHEME SET 55/1/2 (DELHI)

	SET 55/1/2 (DELHI)	T	T
Q No.	Expected Ans wer/ Value Points	Marks	Tot al Marks
1.	V=E-Ir	1	1
2.	Bi and Cu	1/2 + 1/2	1
3.	$I = \frac{P}{V} = \frac{630}{210} = 3A$	1	1
4.	Magnitude of conduction & displacement currents are zero.	1	1
5.	(1, 3) and (2, 4)	1/2 +1/2	1
6.	Heat waves, as they are transverse/electromagnetic in nature	1	1
7.	$A + \delta_m = 2i$	1	1
8.	Spherical.	1	1
9.	Identification of X and Y Function of X and Y X: IF stage Y: Amplifier	1/2 1/2	
	The carrier frequency is changed to a lower frequency by intermediate frequency (IF) stage preceding the detection. It increases the strength of detected signal	1/ ₂ 1/ ₂	2
10.	(i) Val ue of Shunt Resistance 1 (ii) Combined resistance 1		
	(i) Shunt $S = \frac{R_A i_g}{i - i_g}$	1/2	
	$= \frac{1\times 1}{5-1} = 0.25 \Omega$	1/2	
	(ii) Total Resistance $\frac{1}{R_{Total}} = \frac{1}{0.25} + \frac{1}{1} = 5$	1/2	
	$R_{\text{Tot al}} = \frac{1}{5} \Omega = 0.2\Omega$	1/2	2

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11.	Conditions $\frac{1}{2}+\frac{1}{2}$ Rel ati on 1		
	(a) i) Ray of light should travel from denser to rarer mediumii) Angle of incidence should be more than the critical angle.	1/ ₂ 1/ ₂	
	(b) $\mu = \frac{1}{\sin i_c}$ where i_c is the critical angle	1	2
12.	Statement of lenz law Enf and justification 1 1/2 + 1/2		
	The polarity of induced emf is such that it tends to produce a current which opposes the change in magnetic flux that produced it.	1	
	Yes, as the magnetic flux due to vertical component of Earth's magnetic keeps on changing as the metallic rod falls down.	1/2 +1/2	2
13.	(i) Effect on Pright ness of the bulb and reason $\frac{1}{2} + \frac{1}{2}$ (ii) Effect on volt meter reading and reason $\frac{1}{2} + \frac{1}{2}$		
	(i) Decreases When resistance Risincreased, base current i_b will decrease hence collector current will decrease. Brightness of the bulb will decrease.	1/2	
	(ii) Decreases As volt meter is connected across the bulb, therefore its reading will also decrease.	1/2 1/2	2
14.	Det er mi nati on of power 1½ Nat ure 1½		
	Power of convex lens	1/2	
	Power of concave lens		
	$P_{2} =$ D	1/2	
	Po wer of the combination $P=P_1+P_2=+1$ D Nature: Converging	1/2 1/2	2

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	1/2		
Its use to detect the optical signal \frac{1}{2}	2		
Greuit diagram of an illuminated photodiode:			
p-side n-side			1/2
			72
When the photodiode is illuminated with radiations (photon greater than the energy gap (Eg) of the semiconductor, then el			
generated due to the absorption of photons.			
	1- SI DE ED 11 PO	auce t ne	
	o si de to pi o		1
e mf. Hence current flows through the load when connected	_		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus photodiode can be us	he radiation		1
The junction field sends the electrons to n-side and holes to penf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in timensity, if a reverse bias is applied. Thus photodiode can be us photodetector to detect optical signals.	he radiation		1/2
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus photodiode can be us	he radiation		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in t intensity, if a reverse bias is applied. Thus photodiode can be us photodetector to detect optical signals.	he radiation		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in t intensity, if a reverse bias is applied. Thus photodiode can be us photodetector to detect optical signals. OR I important considerations Or der of band gap	he radiation		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in t intensity, if a reverse bias is applied. Thus phot odiode can be us phot odetect or to detect optical signals. OR I inportant considerations Or der of band gap 1. It is a heavily doped p-n junction.	the radiation sed as a		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in t intensity, if a reverse bias is applied. Thus photodiode can be us photodetector to detect optical signals. OR I important considerations Or der of band gap	the radiation sed as a		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus phot odiode can be us phot odetect or to detect optical signals. OR I inportant considerations Or der of band gap 1. It is a heavily doped p-n junction. 2. The reverse breakdown voltages of LEDs are very load. 3. The semiconductor used for fabrication of visible LE atleast have a band gap of 1.8 eV	the radiation sed as a		1
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus photodiode can be use photodetector to detect optical signals. OR I mportant considerations Order of band gap 1. It is a heavily doped p-n junction 2. The reverse breakdown voltages of LEDs are verylo 3. The se miconductor used for fabrication of visible LE	the radiation sed as a		1/2
e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus phot odiode can be us phot odetect or to detect optical signals. OR I inportant considerations Or der of band gap 1. It is a heavily doped p-n junction. 2. The reverse breakdown voltages of LEDs are very load. 3. The semiconductor used for fabrication of visible LE atleast have a band gap of 1.8 eV	the radiation sed as a		1/2
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e mf. Hence current flows through the load when connected. It is easier to observe the change in the current with change in tintensity, if a reverse bias is applied. Thus photodiode can be use photodetector to detect optical signals. OR I mportant considerations Order of band gap 1. It is a heavily doped p-n junction 2. The reverse breakdown voltages of LEDs are verylo 3. The semiconductor used for fabrication of visible LE atleast have a band gap of 1.8 eV (Any two of the above)	the radiation sed as a		1/2

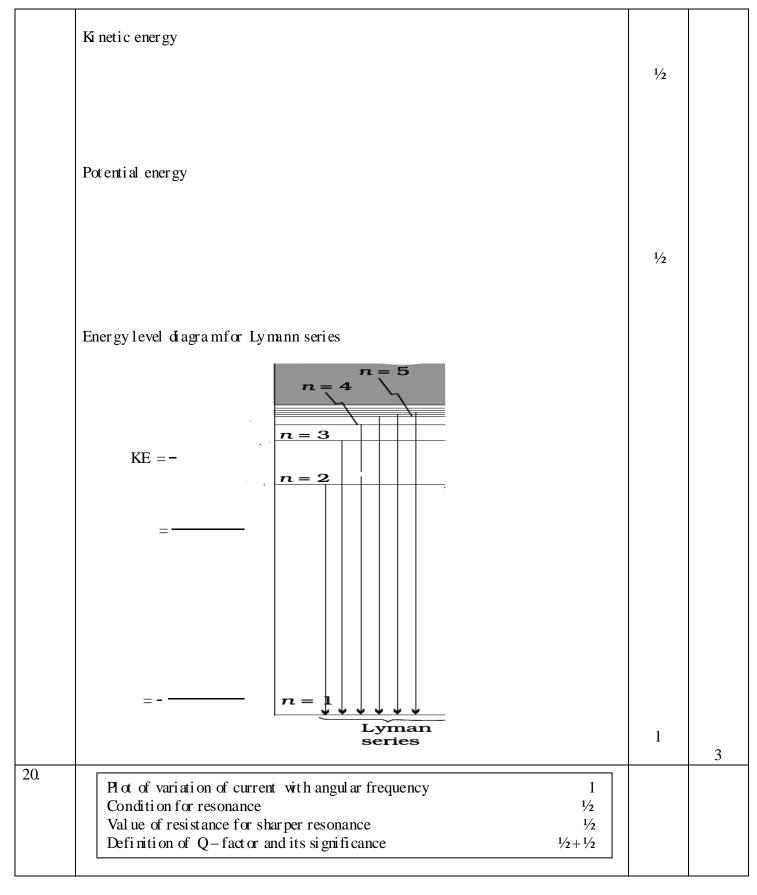
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	(a)		
	Y or Z Z or y X	1 ½	
	$(b)\frac{E_0}{B_0} = c$	1/2	2
17.	(a) Cause of release of energy 1 (b) Proof for independence of nuclear density on mass number 2		
	(a) Since the total initial mass of nuclei on the left side of reaction is greater than the total final mass of nucleus on the right hand side, this difference of mass appears as the energy released.	1	
		1/2	
	$A_{\mathbf{s}} \mathbf{R} = \mathbf{R}_0 \mathbf{A}^{V_{\mathbf{s}}}$	1/2	
		1/2	
		1/2	3
8.	(a) Reasons of failure of wave theory to explain Photoelectric effect. 1 ½ (b) Basic features of Photon picture 1 ½		
	(a) According to wave theory		

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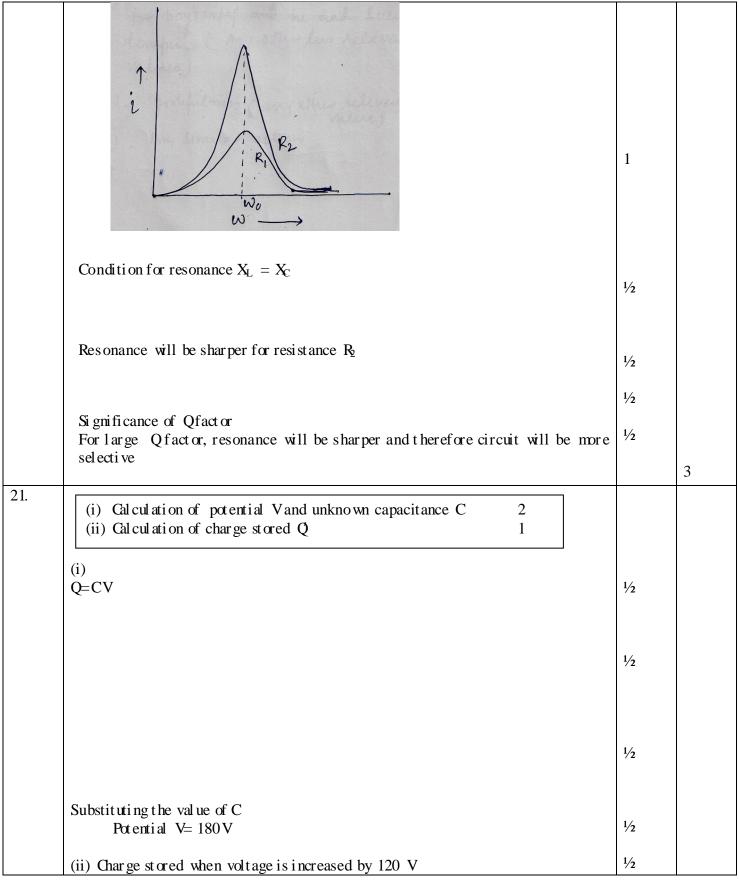
		Ţ		
	(i	proportional to the intensity of incident radiations but it is not observed experimentally. Also maximum kinetic energy of the emitted electrons should not depend upon incident frequency according to wave theory,	1/2	
	(i	but it is not so. El ectron e mmission should take place at all frequencies of radiations i.e. there should not exist the threshold frequency. This fact contradicts experimental observation	1/2	
	(i	ii) There should be a time lagin photoelectric emmission but according to observation photoelectric emmission is instantaneous	1/2	
	(b) A	occording to photon picture		
	(i) Each quantum of radiation has energy h_{ν}	1/2	
	(i	i) In photoelectric effect the electrons in the metal absorbs this quant um of energy ν	1/2	
	(i	ii) When this energy exceeds the minimum energy needed for the electron	1/2	3
19.		Derivation of expression for KE and PE Energy level diagram for Lymann series 1 + 1 1		
			17	
			1/2	
	Fro	m(i) and (ii)	1/2	

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The magnitude of the electric field at the right face is E= 100 NC ¹ Therefore flux through this face Q = 2 = 600 Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1 X X X X X X X X X	1/2	3
(i) Calculation of net electric flux 2 (ii) Galculation of charge 1 (i) The magnitude of the electric field at the left face is E= 50 NC¹ Therefore flux through this face = The magnitude of the electric field at the right face is E= 100 NC¹ Therefore flux through this face Q = 2 = 600 Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required		
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Therefore flux through this face Q = 2 = 600 Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1 X X X X X X X X X X X X X X X X X	1/2	
Therefore flux through this face Q = 2 = 600 Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1 X X X X X X X X X X X X X X X X X		
Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1		
Therefore net flux through the cylinder is (ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1	1/2	
(ii) Charge enclosed by the cylinder C Expression for (i) Current inloop (ii) Force (iii) Power Required 1 X X X X X X X X X		
Expression for (i) Current in loop (ii) Force (iii) Power Required	1/2	
Expression for (i) Current in loop (ii) Force (iii) Power Required 1	1/2	
Expression for (i) Current in loop (ii) Force (iii) Power Required 1	/2	
Expression for (i) Current in loop (ii) Force (iii) Power Required 1	1/2	3
(ii) Force (iii) Power Required 1		
(iii) Power Required		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		

Downloaded From: http://www.cbseportal.com

	The induced emf	1/2	
	(i) Current in the loop	1/2	
	(ii) Force F=i ℓB	1/2	
		1/2	
		1/2	
		1/2	3
23.	Distinction bet ween sky waves and space waves modes of propagation 1 (a) Restriction of sky wave propagation 1 (b) Two examples $\frac{1}{\frac{1}{2}+\frac{1}{2}}$		
	Sky wave communication is achieved by ionospheric reflection of radio waves back towards the earth, while in space wave propagation, the radio waves travel in straight lines from transmitting antenna to the receiving antenna.	1	
	(a) The radio waves of frequencies more than 40 MHz penetrates into the ionosphere.(b) Television broadcast, Microwave link and satellite communication (any two)	1 1/2 + 1/2	3
24.	Determination of (i) Dynamic out put resistance (ii) dc current gain $1/2 + 1/2$ (iii) a c current gain $1/2 + 1/2$		
	(1) Dyna mic out put resistance	1/2	
<u> </u>			

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	$r_0 = \left(\frac{\Delta V_{CE}}{\Delta I_C}\right)$ Ib		
	$I_0 = \left(\Delta I_C \right) I_b$.,	
		1/2	
	= 0.2 mA		
	$\mathbf{r}_0 = 20 \ \mathbf{K} \mathbf{\Omega}$		
	(2) dc current gain, at 10 V, $I_C = 3.6$ mA	1/2 + 1/2	
	$\beta = \frac{I_c}{I_b} = \frac{3.6x10^{-3}}{30x10^{-6}} = 120$		
	(3) ac current gain $\Delta I_h = 40 \ \mu\text{A} - 30 \ \mu\text{A} = 10 \ \mu\text{A}$		
	$\Delta I_c = 4.7 \text{ mA} - 3.6 \text{ mA} = 1.1 \text{ mA}$	1/2	
	$oldsymbol{eta}_{ac} = \; \left(rac{\Delta oldsymbol{I}_c}{\Delta oldsymbol{I}_b} ight)$	1/2	3
	From the graph = $\frac{1.1x10 \cdot 312}{10x10 \cdot 37 \cdot 35} = \frac{1.1x10 \cdot 312}{10x10 \cdot 3} = \frac{1.1x10 \cdot 312}{10x10 \cdot 312} = 1.1x10 \cdot$		
	[NOTE Gredit should also be given to candidate who uses the right procedure, but considers the values slightly different from those used above]		
25.	(a) Relationship bet ween interference pattern and diffraction from each slit 1 (b) Calculation of separation bet ween the position of first maxima of two wavelengths 2		
	 a) In double slit experiment, the pattern on the screen is actually a super position of single slit defraction from each slit and double slit interference pattern. As a result, there appears a broader diffraction peak in which there occur several fringes of smaller widths due to double slit interference. b) Distance of first secondary maximum from centre of the screen 	1	
	$x = -\frac{3}{2} \frac{D\lambda}{a}$ Therefore spacing bet ween first secondary maxima on the screen for two given wavelengths	1/2	
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	3D ~	1/2	
	$\Delta x = \frac{3D}{2a} \mathbf{Q}_2 - \lambda_1^{-1}$ $= \frac{3 \times 1.5}{2 \times 2 \times 10^{-4}} \mathbf{Q} 96 - 590 \times 10^{-9}$ $= \frac{4.5 \times 6 \times 10^{-5}}{4}$ $= 6.75 \times 10^{-5} \text{ m}$	1/2	3
26.	a) Because during thunder stor mear would act as an electrostatic shield b) Dr. Pathak displayed values of safety of human life, helpfulness, empathy and scientific temper. (or any other two relevant values) c) Gratefulness, indebtedness (or any other relevant value) d) Example of any similar action	1 1/2 + 1/2 1 1	4
27.	(a) Working principle of potentioneter Diagram Expression (b) Two possible causes for one sided deflection 1-1 (a) Principle: When a constant current flows through a wire of unifor marea of cross section then potential difference bet ween two points on the wire is directly proportional to length of this section of wire. Va \ell Va \(\ell \)	1	

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			1/2
			1/4
$\Rightarrow \frac{\varepsilon_1}{\varepsilon_2} = \frac{l_1}{l_2}$	L		1/2
$\boldsymbol{\varepsilon}_2 l_2$	2		1
` ' ` '	When the driver cell/source cell has emf less than the	he emf of the cells to be	e 1
	rpared. When the positive end of the potention meter wire is	connected to negative	1
	minal of the cell whose emfisto be compared / dete		1
	OR		
(a) 9:	ntement of Kirchhoff's rule	1/2 + 1/2	
\ /	ning the balance condition in Wheatstone Bridge	2	
(b) Ca	l culation of values of R_1 and R_2	2	
(a)(i) A s	gebraic sum of the currents entering the junction is e	equal to the sum of	1/
currents,	leaving the junction	equal to the sum of	1/2
$\varepsilon_2 = \ell$			
	72		
(ii) The		v decedlessimvelvine	
	Algebraic sum of the changes in potential around an	y closed loop i nvol vi ng	1/2
resist ors			1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero.		5 1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero.		5 1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero.		1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero.		1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero. ively accept the mathematical form of the Kirchho		1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero. ively accept the mathematical form of the Kirchho		1/2
resist ors	Algebraic sum of the changes in potential around any and cells is zero. ively accept the mathematical form of the Kirchho		1/2
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resist ors	Algebraic sum of the changes in potential around any and cells is zero. ively accept the mathematical form of the Kirchho		5 1/ ₂
resistors [Aternat	Algebraic sum of the changes in potential around any and cells is zero. The control of the changes in potential around any and cells is zero. The changes in potential around any and cells is zero. The changes in potential around any and cells is zero.		
resistors [Aternat	Algebraic sum of the changes in potential around any and cells is zero. The mathematical form of the Kirchho sively accept the mathematical form of the Kirchho should be a sum of the kir		1/2
resistors [Aternat	Algebraic sum of the changes in potential around any and cells is zero. The control of the kirchhold of the		
resistors [Alternat	Algebraic sum of the changes in potential around any and cells is zero. The changes in potential around any and cells is zero. The changes in potential around any and cells is zero. The changes in potential around any and cells is zero. The changes in potential around any and cells is zero. ADBA $0 + I_2 R_2 = 0$ $= I_2 R_2$		

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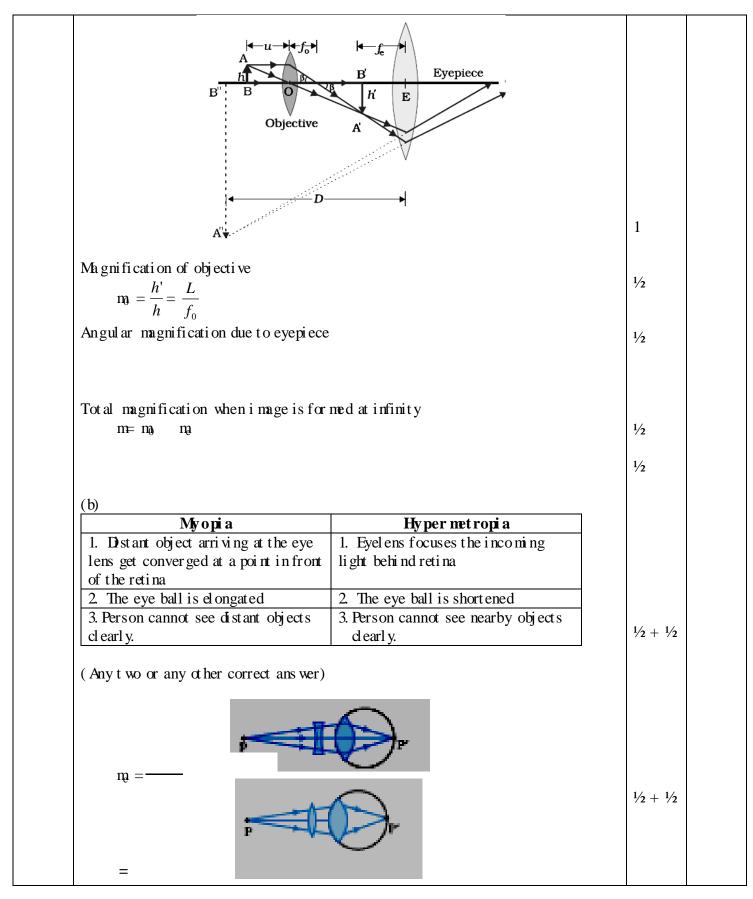
$=> I_{2} R_{1} = I_{1} R_{5}$ $=> \frac{R_{1}}{R_{2}} = \frac{R_{3}}{R_{4}}$ (b) $\frac{R_{1}}{R_{2}} = \frac{40}{60} = \frac{2}{3}$	1/2	
$\frac{R_1 + 10}{R_2} = \frac{60}{40} = \frac{3}{2}$ $\frac{R_1}{R_2} + \frac{10}{R_2} = \frac{3}{2}$	1/2	
$\Rightarrow \frac{2}{3} + \frac{10}{R_2} = \frac{3}{2}$	1/2	
$3 R_2 2$ $=> R_2 = 12 \Omega$	1/2	
Substituting for $R_{\!\!\!2}$ and finding the value of $R_{\!\!\!4}$ $R_{\!\!\!1}$ =8 Ω	1/2	5
(a) Derivation of the expression for the torque with diagram 3 (b) Depiction of the trajectories 2	1	
(a)		

The magnetic field exerts no force on the two arms AD and BC of the loop. Force F_1 acts on arm AB directing into the plane. $F_1 = IbB$		
Force F_2 acts on arm CD directing out of the plane. $F_2 = IbB = F_1$	1/2	
Hence there is a torque on the loop due to forces F_1 and F_2	1/2	
$\frac{a}{2}$ $\frac{a}{2}$		
	1/2	
$= IbB\frac{a}{2} + IbB\frac{a}{2} = I(ab) B = I AB \text{ where } A=ab \text{ is the area of the loop}$ (b)	1/2	
Proton X 22 X X X dentron X 22 X X X	1	
Here $r_1 = r_2$ (Since the momenta of charged particles are equal and they have equal charge, therefore they will describe circular trajectories of same radius) [If the candidate only mentions that they describe circular trajectories without the diagram, one mark should be a warded]	1	5
OR		
(a) Execution of SHM of compass needle in magnetic field 2 Derivation of its time period 1 (b) Finding (i) horizontal component of earth's magnetic field (ii) angle of dip 1+1		
(a) Tor que acting on the compass needle suspended freely in a unifor m magnetic field		
It will be balanced by the restoring torque	1/2	

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For small angle $\sin \theta \approx \theta$		
In equilibirum, the resulting equation of motion		
	1/2	
	1/2	
	1/	
	1/2	
	1/-	
	1/2	
	1/2	
[If the student just writes that the needle,		
(i) When slightly disturbed from its stable position experiences a torque due to the magnetic field and		
(ii) writes the expression for this torque,		
Award $(1 + 1 = 2)$ marks]		
$\Rightarrow \frac{d^2\theta}{dt^2} = -\left(\frac{MB}{I}\right)$ (b) (i) Horizontal component of Earth's magnetic field=0	1	
1 1 4-U	1	
as $\frac{d^2 v}{(i\hbar r)^2}$ The value of angle of dip at that place = 90°		5
$\Rightarrow \qquad {}^{2}=\frac{MB}{I}$		
29.		
(a) Ray diagramshowing image for mation Derivation of expression for magnification 1		
(b) Distinction bet ween my opi a and hyper metropia 1		
Correction of defects by diagram 1		

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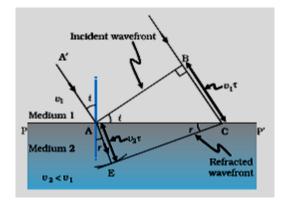
My opi a can be corrected by	Hyper metropia can be corrected by
• 1	• 1
interposing a concave lens bet ween	interposing a convex lens bet ween
eye and object	eye and object

[Award only half mark if diagrams not drawn, award full mark even if explanation is not written]

OR

(a) Statement of Huygen's principle	1
Dagram	1
Verification of Snell's law	1
(b) Expl anati on of (i) and (ii)	1+1

(a) According to Huygens principle, each point of the wavefront is the source of a secondary disturbance and the wavelets emanating from these points spread out in all directions with the speed of the wave. A common tangent to all these wavelets, gives the new position of the wavefront at a later time.



Verification of Snell's law

Fromfigure

$$\sin i = \frac{BC}{AC} = \frac{v_1 t}{AC}$$

$$\sin r = \frac{AE}{AC} = \frac{v_2 t}{AC}$$

$$\frac{\sin i}{\sin r} = \frac{v_1}{v_2} = \mu$$

(b) Yes,

(i) Reflection and refraction arise through interaction of incident light with the atomic constituents of matter. Atoms may be viewed as oscillators, which take up the frequency of the external agency (light) causing forced oscillations. The frequency of light emitted by a charged oscillator equals its frequency of

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5

1

1/2

1/2

oscillation. Thus, the frequency of scattered light equals the frequency of incident light. [Any other correct explanation]	1	
(ii) No. Energy carried by a wave depends on the amplitude of the wave, not on the speed of wave propagation.	1	5

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